Case No. 10200/101

DECLARATION FOR PATENT APPLICATION

As a below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name.

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled Methods of Forming Semiconductor Structures Having Reduced Defects, and Articles and Devices Formed Thereby, the specification of which:

\boxtimes	is attached hereto.			
	was filed on as Ap	oplication Serial No		
	and was amended on	(if applicable).		
	nat I have reviewed and un amendment referred to ab	nderstand the contents of the above-ic ove.	dentified specification	n, including the claims, as
I acknowledge t Regulations, § 1		nation which is material to the patent	tability as defined in	Title 37, Code of Federal
inventor's certif United States, li	icate or § 365(a) of any E sted below and have also i	nder 35 U.S.C. § 119(a)-(d) or § 365 PCT International application which of dentified below, by checking the box, in having a filing date before that of the	designated at least o , any foreign applicat	one country other than the ion for patent or inventor's
Prior Foreign A	oplication(s)			Priority Claimed
(Number) (Country)	(Day/Month/Ye	ear Filed)	Yes No
I hereby claim application designs not disclosed	gnating the United States, I in the prior United States	(Filing Date) C. § 120 of any United States application in the disclose information which is material	t matter of each of the e manner provided b	e claims of this application y the first paragraph of 35
		date of the prior application and the		
(Applic	ation Serial No.)	(Filing Date)	(Status-paten	ted, pending, abandoned)
belief are believ the like so made	ed to be true; and further t are punishable by fine or	erein of my own knowledge are true a that these statements were made with the imprisonment, or both, under Section ardize the validity of the application or	the knowledge that w 1001 of Title 18 of the	villful false statements and he United States Code and
Inventor's Signa	ture	CM Mys	Date:	2/10/01
Full name of sol				
Residence	e or first inventor	Hanna A. Bamnolker		
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Citizenship Post Office Add				

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			Case No	. 10200/1	<u>01</u>
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